



DMP3018SFVQ

PowerDI3333-8 (Type UX)

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
001/	12mΩ @ V _{GS} = -10V	-35A
-30V	21mΩ @ V _{GS} = -4.5V	-25A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Backlighting
- **Power Management Functions**
- **DC-DC** Converters

Features and Benefits

100% Unclamped Inductive Switching (Test in Production) -Ensures More Reliable and Robust End Application

30V P-CHANNEL ENHANCEMENT MODE MOSFET

- Low R_{DS(ON)} ensures on-state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

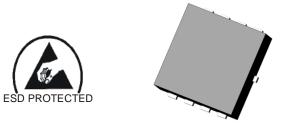
Mechanical Data

- Case: PowerDI[®]3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram

Pin1

- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

Bottom View



Top View

Ordering Information (Note 5)

	Part Number	Case	Packaging			
	DMP3018SFVQ-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel			
	DMP3018SFVQ-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel			
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

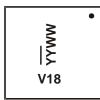
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds. Automotive products are AEC-Q101 gualified and are PPAP capable. Refer to https://www.diodes.com/guality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



V18 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

G Gate Protection S

Equivalent Circuit

Diode



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Drain Current (Note 7) V_{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	Ι _D	-11 -9	А
Continuous Drain Current (Note 8) V_{GS} = -10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	I _D	-35 -25	А
Maximum Continuous Body Diode Forward Current (Note 8)			Is	-30	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-70	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			I _{SM}	-70	А
Avalanche Current (Note 9) L = 1mH			I _{AS}	-14	А
Avalanche Energy (Note 9) L = 1mH			E _{AS}	104	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	133	°C/W
Total Power Dissipation (Note 7)	T _A = +25°C	PD	1.9	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	R _{0JA}	66	°C/W
Total Power Dissipation (Note 8)	PD	30	W	
Thermal Resistance, Junction to Case (Note 8)	R _{θJC}	3.7	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

	-	-				-	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30		_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS		—	-1	μA	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	—	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0		-3.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance			—	12	mΩ	$V_{GS} = -10V, I_D = -11.5A$	
	R _{DS(ON)}		—	21	11122	$V_{GS} = -4.5V, I_D = -8.5A$	
Diode Forward Voltage	V _{SD}		-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	Ciss		2147	_	pF		
Output Capacitance	Coss		407	—	pF	− V _{DS} = -15V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance	Crss		358	—	pF		
Gate Resistance	Rg		24	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -5V)	Qg	_	28	_	nC		
Total Gate Charge (V _{GS} = -10V)	Qg		51	_	nC	VDS = -15V. ID = -11.5A	
Gate-Source Charge	Qgs		6.6	—	nC	$v_{DS} = -15v, I_D = -11.5A$	
Gate-Drain Charge	Q _{gd}		15	—	nC	1	
Turn-On Delay Time	t _{D(ON)}	-	7.8	_	ns		
Turn-On Rise Time	t _R	-	19.9	—	ns	V_{DD} = -15V, V_{GS} = -10V, R_{G} = 6 Ω , I_{D} = -11.5A	
Turn-Off Delay Time	t _{D(OFF)}	_	57.5	_	ns		
Turn-Off Fall Time	t _F	_	42.8	_	ns		
Reverse Recovery Time	t _{RR}	_	21.5		ns		
Reverse Recovery Charge	Q _{RR}	-	11.6		nC	I _S = -11.5A, dl/dt = 100A/μs	

6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

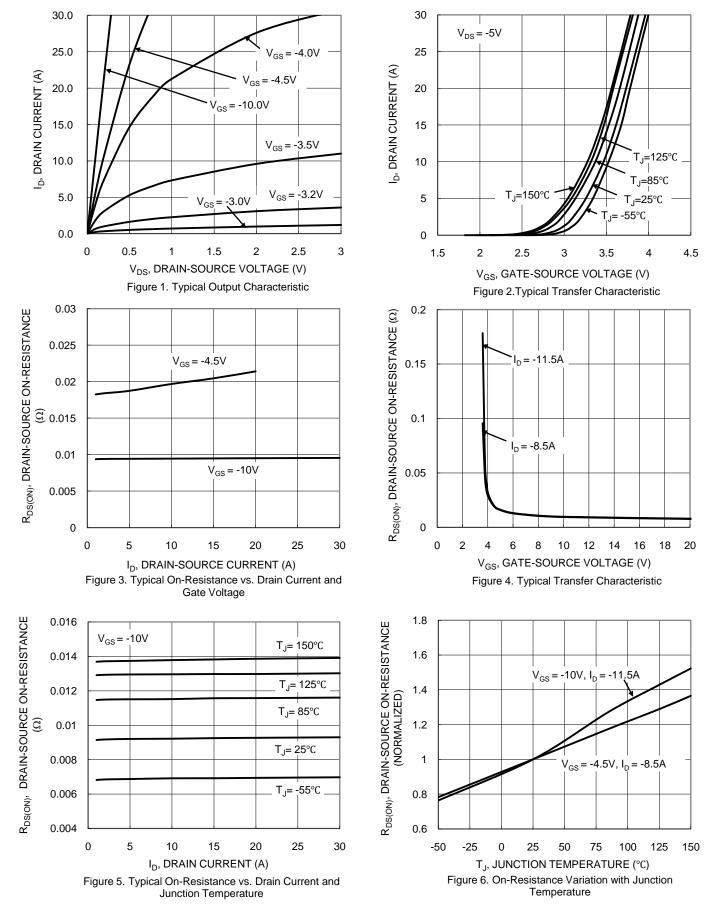
8. Thermal resistance from junction to soldering point (on the exposed drain pad).

9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

Shot duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



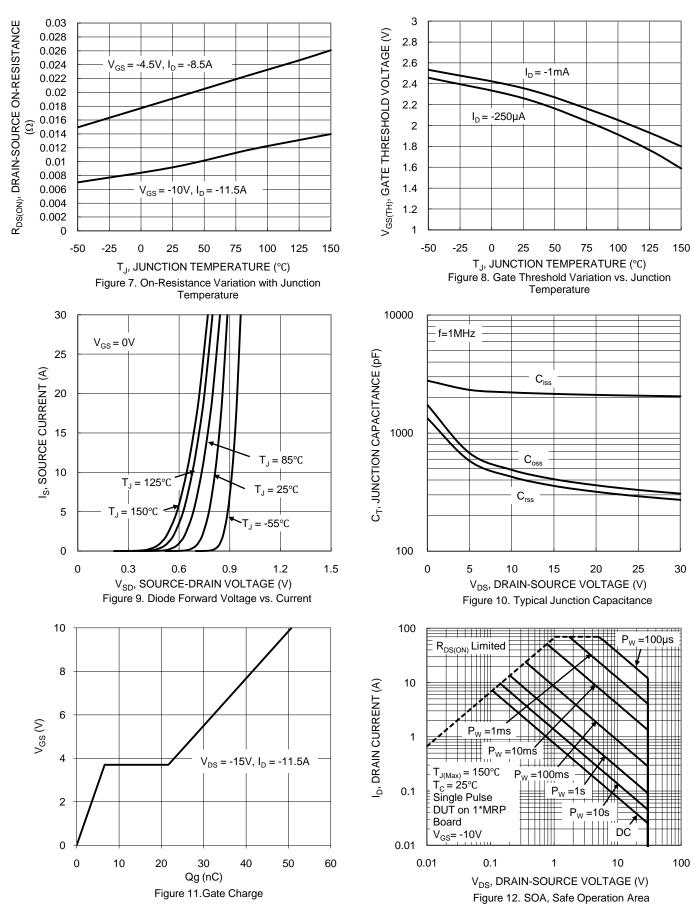
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DMP3018SFVQ Document number: DS40798 Rev. 2 - 2

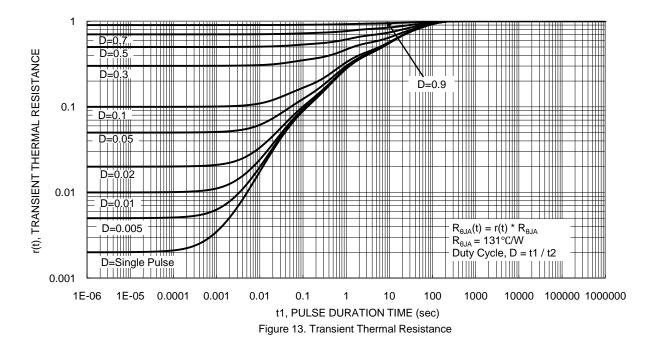


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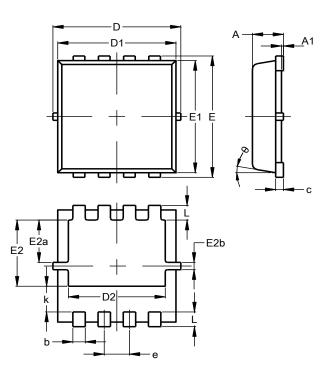






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



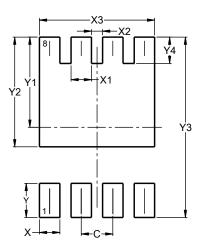
	PowerDI3333-8 (Type UX)					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	2.95 3.15 3.0				
D2	2.30 2.70		2.50			
E	3.20	3.20 3.40				
E1	2.95	3.05				
E2	1.60 2.00 1.80					
E2a	0.95 1.35 1.1					
E2b	0.10 0.30 0.20					
е	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

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Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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